Ref #	Hits	Search Query	DBs	Default Operat or	Plural s	Time Stamp
L1	0	10/707029	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 12:34
L2	0	"10707029"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 14:20
L3	270	(deep near3 trench with capacitor) with electrode	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 15:40
L4	81	3 and (deep near3 trench with capacitor) with node	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 15:42
L5	62	4 and (deep near3 french with capacitor) with dielectric	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 14:23
L6	2	5 and (deep near3 trench with capacitor) with spacer	US-PGPU B; USPAT; EPO; JPO	OR	ON.	2005/10/05 14:23
L7	1	"6472702".PN.	USPAT; USOCR	OR	ON	2005/10/05 14:32
L8	1	"6255224".PN.	USPAT; USOCR	OR	ON	2005/10/05 14:33
L9	1	"6181014".PN.	USPAT; USOCR	OR	ON	2005/10/05 14:33
L10	1	"5888864".PN.	USPAT; USOCR	OR	ON	2005/10/05 14:34
L11	1	"5198386".PN.	USPAT; USOCR	OR	ON	2005/10/05 14:35
L12	1	"6436760".PN.	USPAT; USOCR	OR	ON	2005/10/05 14:35
L13	1	"6472702".PN.	USPAT; USOCR	OR	ON	2005/10/05 14:35

L14	1710	(trench near3 capacitor) with electrode	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 15:41
L15	260	14 with oxide	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 15:42
L16	17	15 with (oxidation oxidizing oxidization)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/10/05 15:44

